

Audio

Order code	Manufacturer code	Description
82-2154	n/a	NJM2073D 2W STEREO AMPLIFIER

Audio	Page 1 of 8
The enclosed information is believed to be correct, Information may change 'without notice' due to product improvement. Users should ensure that the product is suitable for their use. E. & O. E.	Revision A 12/12/2006

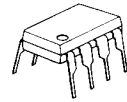
NJM2073

The NJM2073 is a monolithic integrated circuit in 8 lead dual-in-line package, which is designed for dual audio power amplifier in portable radio and handy cassette player.

■ Features

- Supply Voltage $V^+ = 1.8 \sim 15V$
- Low Crossover Distortion
- Low Supply Current
- Bridge or Stereo Configuration
- No Turn-on Noise

■ Package Outline



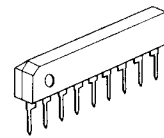
NJM 2073 D



NJM 2073 M

■ Absolute Maximum Ratings ($T_a = 25^\circ C$)

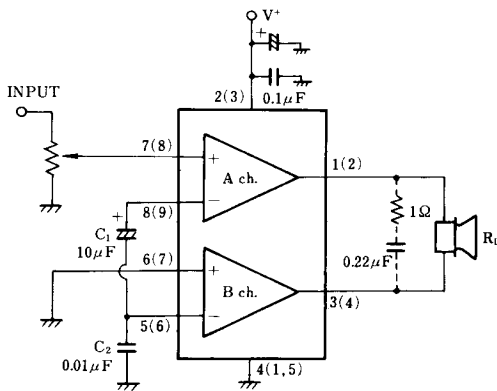
Supply Voltage	V^+	15V
Output Peak Current	I_{OP}	1A
Power Dissipation	P_D (D-Type)	700mW
	(S-Type)	700mW
	(M-Type)	300mW
Input Voltage Range	V_{IN}	$\pm 0.4V$
Operating Temperature Range	T_{opr}	$-20 \sim 75^\circ C$
Storage Temperature Range	T_{stg}	$-40 \sim 125^\circ C$



NJM 2073 S

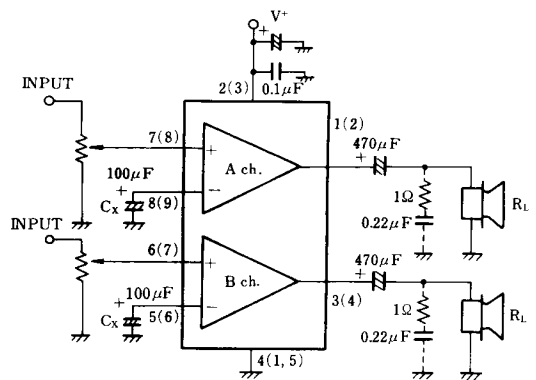
■ Typical Application & Test Circuit

Fig.1 BTL Configuration



note: pin No. to D,M-Type
() to S-Type

Fig.2 Stereo Configuration



■ Electrical Characteristics D,S-Type (Ta=25°C)

(1) BTL Configuration (Test Circuit Fig. 1)

Parameter	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Operating Supply Voltage	V ⁺		1.8	—	15	V
Supply Current	I _{cc}	R _L =∞	—	6	9	mA
Output Offset Voltage (Between the Outputs)	ΔV _o	R _L =8Ω	—	10	50	mV
Input Bias Current	I _B		—	100	—	nA
Output Power	P _o	THD=10%, f=1kHz				
	P _o	V ⁺ =9V, R _L =16Ω (Note)	—	2.0	—	W
	P _o	V ⁺ =6V, R _L =8Ω (Note)	0.9	1.2	—	W
	P _i	V ⁺ =4.5V, R _L =8Ω	—	0.6	—	W
	P _o	V ⁺ =4.5V, R _L =4Ω (Note)	—	0.8	—	W
	P _o	V ⁺ =3V, R _L =4Ω	200	300	—	mW
	P _o	V ⁺ =2V, R _L =4Ω	—	80	—	mW
		THD=1%, f=40Hz~15kHz				
	P _o	V ⁺ =6V, R _L =8Ω	—	1.0	—	W
	P _o	V ⁺ =4.5V, R _L =4Ω	—	0.6	—	W
Total Harmonic Distortion	THD	P _o =0.5W, R _L =8Ω, f=1kHz	—	0.2	—	%
Close Loop Voltage Gain	A _v	f=1kHz	41	44	47	dB
Input Impedance	Z _{IN}	f=1kHz	100	—	—	kΩ
Equivalent Input Noise Voltage	V _{Ni1}	R _s =10kΩ, A Curve	—	2	—	μV
	V _{Ni2}	R _s =10kΩ, B=22Hz~22kHz	—	2.5	—	μV
Ripple Rejection	RR	f=100Hz	—	40	—	dB
Cutoff Frequency	f _H	A _v =-3dB from f=1kHz, R _L =8Ω, P _o =1W	—	130	—	kHz

(Note) At on PC Board

(2) Stereo Configuration (Test Circuit Fig. 2)

Parameter	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Operating Supply Voltage	V ⁺		1.8	—	15	V
Output Voltage	V _o		—	2.7	—	V
Supply Current	I _{cc}	R _L =∞	—	6	9	mA
Input Bias Current	I _B		—	100	—	nA
Output Power (Each Channel)		THD=10%, f=1kHz				
	P _o	V ⁺ =6V, R _L =4Ω (Note)	0.5	0.65	—	W
	P _o	V ⁺ =4.5V, R _L =4Ω	—	0.32	—	W
	P _o	V ⁺ =3V, R _L =4Ω	—	120	—	mW
	P _o	V ⁺ =2V, R _L =4Ω	—	30	—	mW
		THD=1%, f=1kHz				
	P _o	V ⁺ =6V, R _L =4Ω	—	500	—	mW
	P _o	V ⁺ =4.5V, R _L =4Ω	—	250	—	mW
Total Harmonic Distortion	THD	P _o =0.4W, R _L =4Ω, f=1kHz	—	0.25	—	%
Voltage Gain	A _v	f=1kHz	41	44	47	dB
Channel Balance	ΔA _v		—	—	±1	dB
Input Impedance	Z _{IN}	f=1kHz	100	—	—	kΩ
Equivalent Input Noise Voltage	V _{Ni1}	R _s =10kΩ, A Curve	—	2.5	—	μV
	V _{Ni2}	R _s =10kΩ, B=22Hz~22kHz	—	3	—	μV
Ripple Rejection	RR	f=100Hz, C _x =100μF	24	30	—	dB
Cutoff Frequency	f _H	A _v =-3dB from f=1kHz R _L =8Ω, P _o =250mW	—	200	—	kHz

(Note) At on PC Board

■ Electrical Characteristics M-Type (Ta=25°C)

(1) BTL Configuration (Test Circuit Fig. 1)

Parameter	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Operating Supply Voltage	V ⁺		1.8	—	15	V
Supply Current	I _{CC}	R _L = ∞	—	6	9	mA
Output Offset Voltage (Between the Outputs)	ΔV _O	R _L = 8Ω	—	10	50	mV
Input Bias Current	I _B		—	100	—	nA
Output Power		THD=10%, f=1kHz				
	P _O	V ⁺ =6V, R _L =16Ω (Note)	—	0.8	—	W
	P _O	V ⁺ =4V, R _L =8Ω (Note)	350	460	—	mW
	P _O	V ⁺ =3V, R _L =4Ω (Note)	200	300	—	mW
	P _O	V ⁺ =2V, R _L =4Ω	—	80	—	mW
		THD=1%, f=40Hz~15kHz				
	P _O	V ⁺ =4V, R _L =8Ω	—	380	—	mW
Total Harmonic Distortion	THD	V ⁺ =4V, R _L =8Ω, P _O =200mW, f=1kHz	—	0.2	—	%
Close Loop Voltage Gain	A _V	f=1kHz	41	44	47	dB
Input Impedance	Z _{IN}	f=1kHz	100	—	—	kΩ
Equivalent Input Noise Voltage	V _{NI1}	R _S =10kΩ, A Curve	—	2	—	μV
	V _{NI2}	R _S =10kΩ, B=22Hz~22kHz	—	2.5	—	μV
Ripple Rejection	RR	f=100Hz	—	40	—	dB
Cutoff Frequency	f _H	A _V =-3dB from f=1kHz, R _L =16Ω, P _O =0.5W	—	130	—	kHz

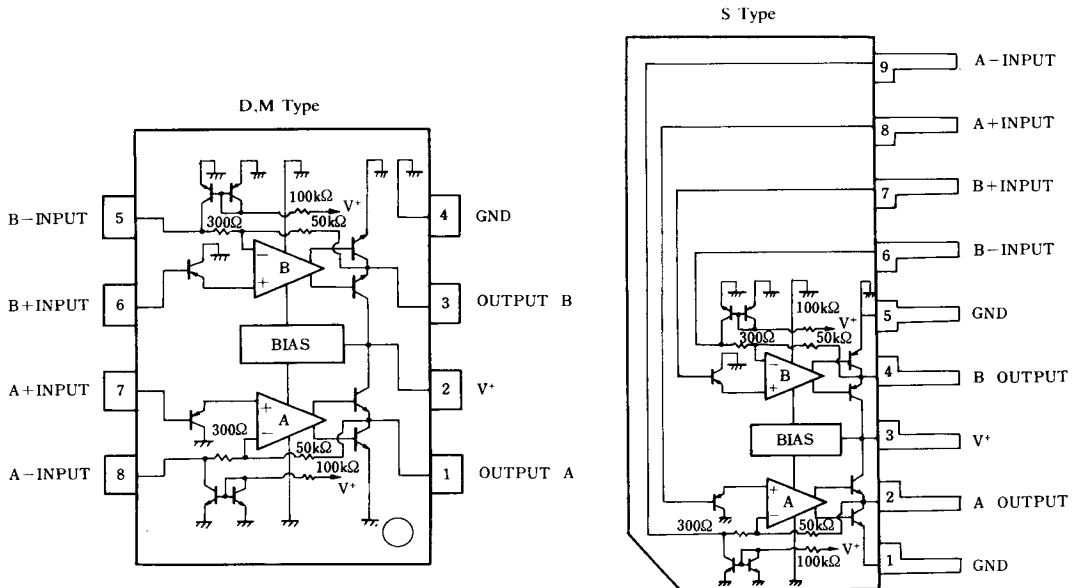
(Note) At on PC Board

(2) Stereo Configuration (Test Circuit Fig. 2)

Parameter	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Operating Supply Voltage	V ⁺		1.8	—	15	V
Output Voltage	V _O		—	2.7	—	V
Supply Current	I _{CC}	R _L = ∞	—	6	9	mA
Input Bias Current	I _B		—	100	—	nA
Output Power (Each Channel)		THD=10%, f=1kHz				
	P _O	V ⁺ =6V, R _L =16Ω	—	240	—	mW
	P _O	V ⁺ =5V, R _L =8Ω (Note)	—	270	—	mW
	P _O	V ⁺ =4V, R _L =4Ω (Note)	180	250	—	mW
	P _O	V ⁺ =3V, R _L =4Ω	—	120	—	mW
	P _O	V ⁺ =2V, R _L =4Ω	—	30	—	mW
		THD=1%, f=1kHz				
	P _O	V ⁺ =4V, R _L =4Ω	—	180	—	mW
Total Harmonic Distortion	THD	V ⁺ =4V, R _L =4Ω, P _O =150mW, f=1kHz	—	0.25	—	%
Voltage Gain	A _V	f=1kHz	41	44	47	dB
Channel Balance	ΔA _V		—	—	±1	dB
Input Impedance	Z _{IN}	f=1kHz	100	—	—	kΩ
Equivalent Input Noise Voltage	V _{NI1}	R _S =10kΩ, A Curve	—	2.5	—	μV
	V _{NI2}	R _S =10kΩ, B=22Hz~22kHz	—	3	—	μV
Ripple Rejection	RR	f=100Hz, C _X =100μF	24	30	—	dB
Cutoff Frequency	f _H	A _V =-3dB from f=1kHz, R _L =16Ω, P _O =125mW	—	200	—	kHz

(Note) At on PC Board

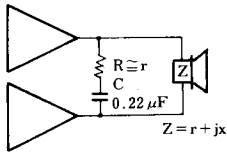
■ Block Diagram & Connection Diagram



■ Circuit for Prevent from Parasitic Oscillation

Put $1\Omega + 0.22\mu\text{F}$ on parallel to load, if the load is speaker. Recommend putting $0.1\mu\text{F}$ and more than $100\mu\text{F}$ capacitors with good high frequency characteristics in to near ground and supply voltage pins.

In BTL operation of less than 2V supply voltage, parasitic oscillation may be occurred with $R = 1\Omega$. And so recommended R to be the same valve of pure resistance(r) when it is lower than 3V.



■ Muting Circuit

When Mute ON, OUTPUT level saturates to GND side.

Fig.3 BTL Configuration

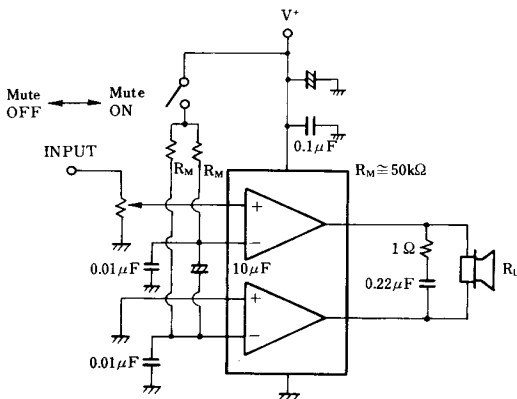
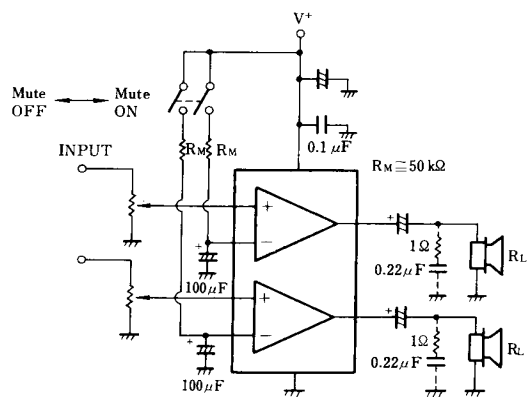
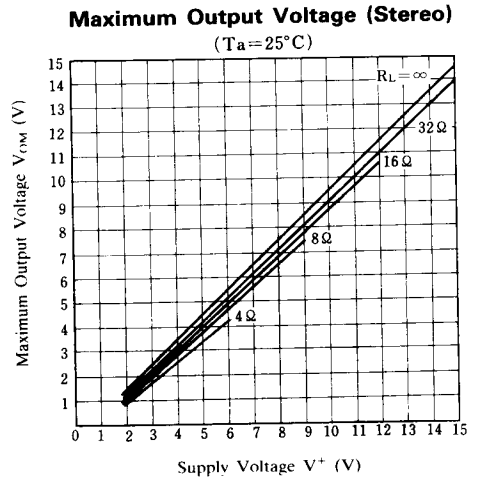
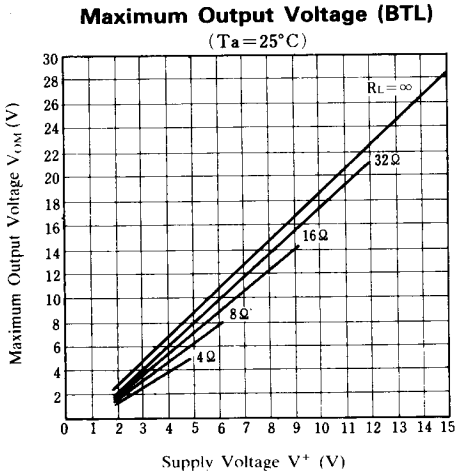
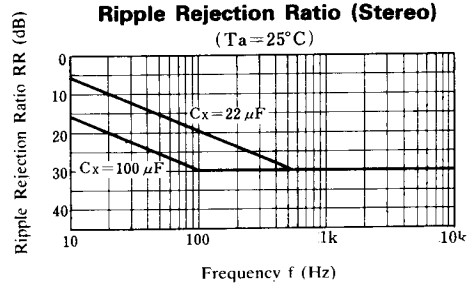
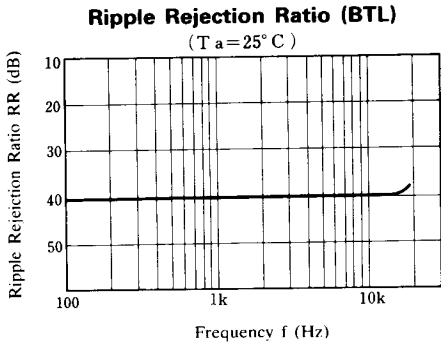
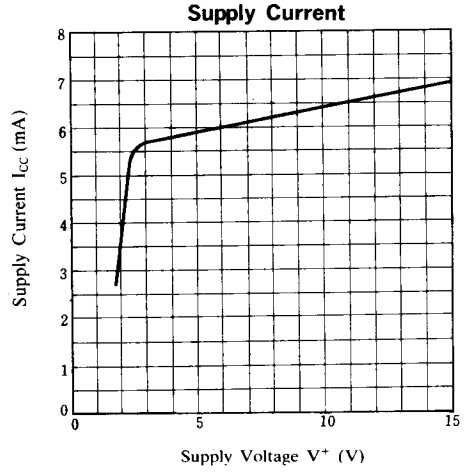
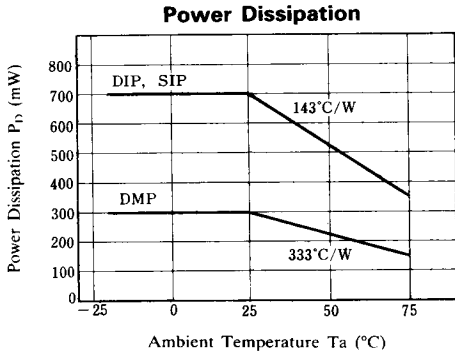


Fig.4 Stereo Configuration



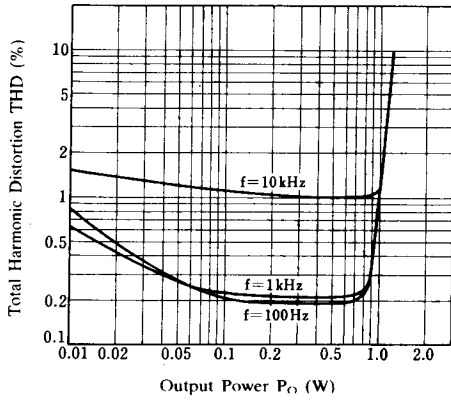
■ Typical Characteristics



■ Typical Characteristics

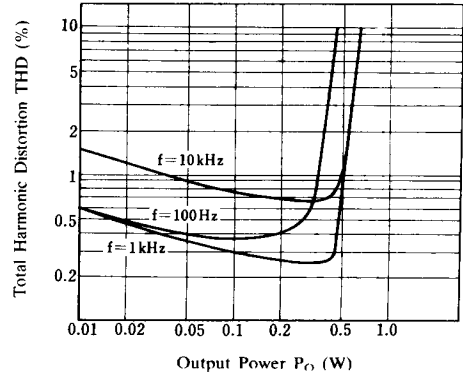
Total Harmonic Distortion (BTL)

($V^+ = 6V, R_L = 8\Omega$)



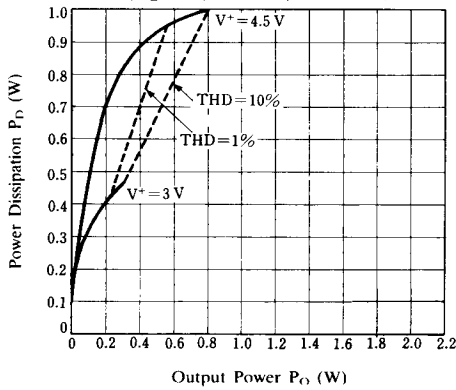
Total Harmonic Distortion (Stereo)

($V^+ = 6V, R_L = 4\Omega$)



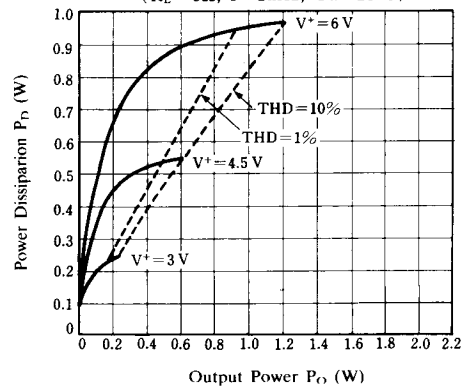
Power Dissipation vs. Output Power (BTL)

($R_L = 4\Omega, f = 1kHz, T_a = 25^\circ C$)



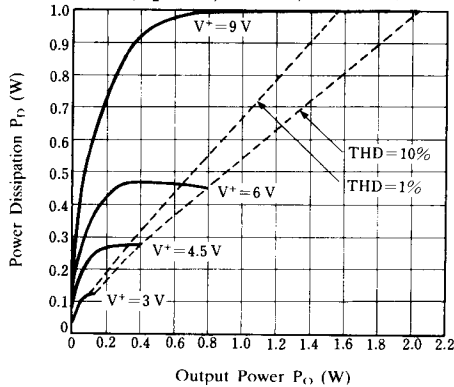
Power Dissipation vs. Output Power (BTL)

($R_L = 8\Omega, f = 1kHz, T_a = 25^\circ C$)



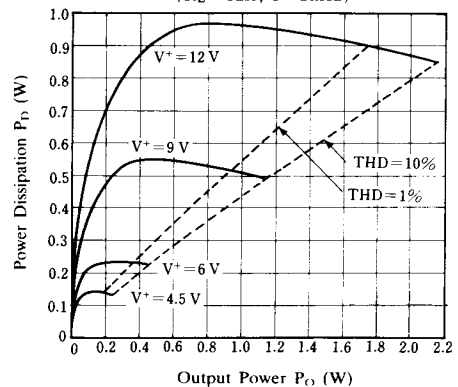
Power Dissipation vs. Output Power (BTL)

($R_L = 16\Omega, f = 1kHz, T_a = 25^\circ C$)



Power Dissipation vs. Output Power (BTL)

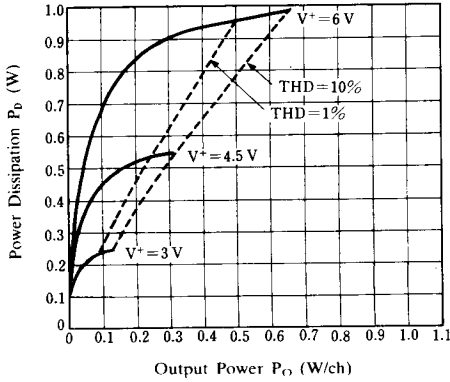
($R_L = 32\Omega, f = 1kHz$)



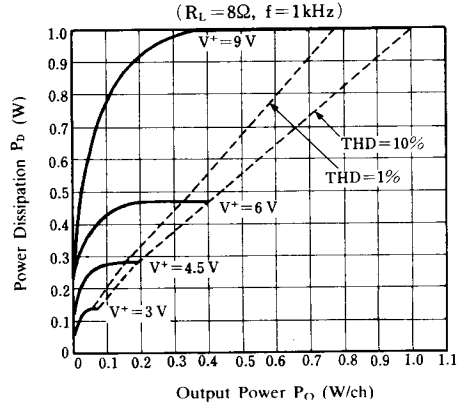
5

■ Typical Characteristics

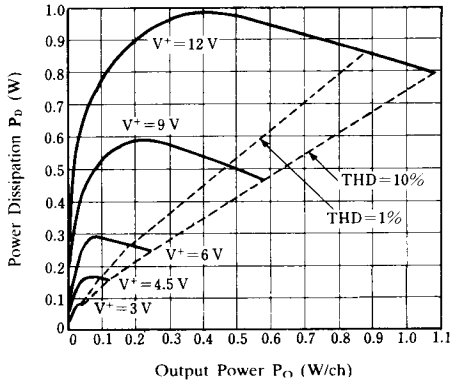
Power Dissipation vs. Output Power (Stereo)
($R_L = 4\Omega$, $f = 1\text{kHz}$)



Power Dissipation vs. Output Power (Stereo)



Power Dissipation vs. Output Power (Stereo)
($R_L = 16\Omega$, $f = 1\text{kHz}$)



Power Dissipation vs. Output Power (Stereo)
($R_L = 32\Omega$, $f = 1\text{kHz}$)

